

Accurate electron channeling contrast analysis of a low angle sub-grain boundary



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ABSTRACT

High resolution selected area channeling pattern (HR-SACP) assisted accurate electron channeling contrast imaging (A-ECCI) was used to unambiguously characterize the structure of a low angle grain boundary in an interstitial-free-steel. The boundary dislocations were characterized using TEM-style contrast analysis. The boundary was determined to be tilt in nature with a misorientation angle of 0.13° consistent with the HR-SACP measurements. The results were verified using high accuracy electron backscatter diffraction (EBSD), confirming the approach as a discriminating tool for assessing low angle boundaries.

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The development and structure of low angle grain boundaries play critical roles in a wide range of materials processes and behaviors. Examples of where such boundaries are inexorably linked to behavior include the development of low energy dislocation structures during static and dynamic recovery, creation of dislocation cell structures during fatigue deformation, and many creep processes.

In order to fully understand many of these phenomena, it is necessary to characterize low angle boundaries in terms of their misorientations and dislocation structure. In many cases such studies have been carried out using transmission electron microscopy (TEM) in conjunction with electron diffraction, which offers direct imaging combined with high accuracy orientation measurements [1–9]. Nevertheless, TEM is limited by the need to create, and the potential artifacts of, thin foils [10,11].

Over the past two decades electron backscattered diffraction (EBSD) and associated orientation mapping has been used to rapidly map crystal orientations at the surfaces of bulk materials, allowing sub grain structures to be readily observed over large areas [12,13]. However, this approach is limited in that it does not allow direct imaging and characterization of the defects associated with low angle boundaries and, in most cases, is hampered

by the inherent limits in precision of the Hough transform based approach to solving EBSD patterns [14–16].

Electron channeling contrast imaging (ECCI) is a powerful technique for observing and characterizing crystallographic defect such as dislocations, stacking faults, and grain boundaries in scanning electron microscopy (SEM) [17–23]. In order to detect defects, ECCI uses the fact that the backscattered electron yield is very sensitive to the angle between the incident beam and the crystal lattice. ECC can be optimized by controlling the channeling conditions to so called two-beam conditions, allowing the characterization of crystallographic planes responsible for the channeling effect and facilitating TEM-style contrast analysis [17,24,25].

A novel approach to control the channeling conditions for performing ECCI with an accuracy of 0.04° has recently been developed. This approach is based on an innovative procedure for collecting high angular and spatial resolution (about 500 nm) selected area channeling patterns (HR-SACPs) on the GEMINI-type electron column [26]. This technique, called Accurate ECCI (A-ECCI), was applied to unambiguously characterize screw dislocations in fine-grained IF-Steel using the $\mathbf{g}\cdot\mathbf{b}=0$ invisibility criterion [17].

In this study we present a new method for characterizing the nature of low angle boundaries by combining the direct imaging and characterization of dislocations using ECCI with high precision misorientation measurement using HR-SACPs. A-ECCI is used to analyze a low sub-grain boundary located in a specific grain of a polycrystalline bcc 2%Si IF steel slightly deformed in tension. Following the deformation process the specimen surface was first

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mechanically polished and then finished electrolytically. The study was carried out on a Zeiss AURIGA 40 FIB SEM, where HR-SACPs and ECC images were collected using an 11 mm² four-quadrant Si-diode backscattered electron detector. The microscope was operated at 20 kV and a 7 mm working distance. Prior to the HR-SACP collection, the sample was tilted to 70° to facilitate determination of the orientation of the region of interest by EBSD. Since A-ECCI is carried out at low tilt, simulated EBSD data were used to approximate the orientation of the crystal of interest at 0 tilt. Specific channeling conditions were then accurately established by HR-SACP in conjunction with tilt and rotation of the sample.

Fig. 1a shows an HR-SACP taken from the grain of interest. This HR-SACP, indicated by the white square, is superimposed on a Kikuchi pattern dynamically simulated from orientation data determined by EBSD using the “Esprit DynamicS” software from Bruker. The position of the un-rocked beam, corresponding also to the microscope optic axis, is identified by a cross, and indicates a beam direction close to [232]. The coincidence between the experimentally collected HR-SACP and the surrounding simulated EBSD pattern is remarkable and allows precise determination of the orientation of the crystal relative to the optic axis, facilitating the establishment of two-beam channeling conditions.

The ECC image of the grain (Fig. 1b) reveals contrast from dislocations in relation with carbide particles throughout the structure. The change in the grain contrast from dark to bright and the series of aligned dislocations clearly reveal the location of the sub-boundary. Fig. 1b-3 shows a magnified secondary electron image of the sub-grain boundary with the particles indicated by

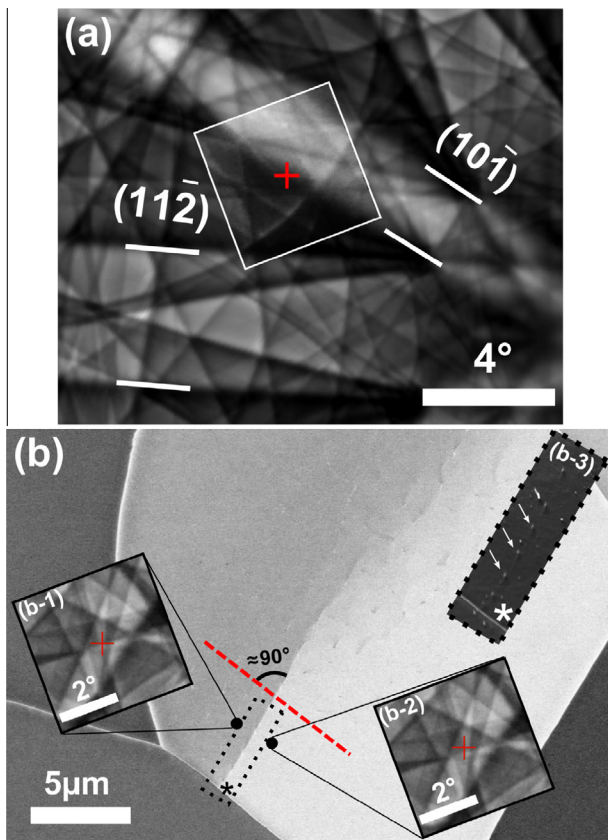


Fig. 1. (a) HR-SACP superimposed on a dynamical Kikuchi pattern simulated with the “Esprit DynamicS” software from Bruker. The red crosses in the HR-SACPs indicate the microscope optic axis. (b) ECC image of a sub-grain boundary showing HR-SACPs acquired from each side of the boundary reveals the direction of pattern shift (dotted red line) and the misorientation angle ($\approx 0.13^\circ$). (For interpretation of the references to color in this figure legend, the reader is referred to the web version of this article.)

white arrows close to the positions of the dislocations in the boundary.

Two HR-SACPs (b-1 and b-2), collected from the indicated areas on either side of the boundary, are also shown Fig. 1b. Superposition of the two HR-SACPs using the image analysis software “ImageJ” indicates that the direction of pattern shift is almost perpendicular to the sub-boundary trace, consistent with a tilt boundary made up of dislocation lines roughly parallel to the sample surface. Cross-correlation of the images shows the shift is 3.08 pixels. Knowing that the HR-SACPs are composed of 101×101 pixels and have an angular range of $\approx 4.4^\circ$ (at $WD = 7$ mm), this shift corresponds to a disorientation across the sub-grain boundary of $\approx 0.13^\circ$ between the points indicated.

Dislocations in bcc IF-steel are expected to have a Burgers vector $b = \frac{1}{2} \langle 111 \rangle$. Fig. 2 shows an HR-SACP assisted A-ECCI analysis of the dislocations making up the sub-grain boundary. Fig. 2a shows HR-SACPs of four channeling conditions used in the analysis superimposed on a dynamical simulation of the Kikuchi pattern for 0° tilt. The sample was tilted up to 20° and rotated to reach the different channeling conditions (g-vectors), images of which are shown in Fig. 2b–e. According to Wilkinson et al. [27] the visibility of depth of dislocations in ECC images is approximately $5\xi_g$, where ξ_g is the extinction distance of the diffracted wave. At 20 kV with $g = (01-1)$ the extinction distance is $\xi_g = 14.2$ nm. Using the projected length of the dislocations along the boundary (≈ 480 nm) and using a visibility depth of dislocations of $5\xi_g = 71$ nm, the inclination angle of the dislocations line was approximated to be $\approx 8^\circ$ from the surface. The dislocation line direction, characterized by fading dashed lines that indicate the sense of inclination, is plotted on the stereographic projection in Fig. 2f. The trace and inclination correspond to the $[10-1]$ direction, indicating the dislocations are not $\langle 111 \rangle$ screw dislocations. The dislocations were characterized applying the $\mathbf{g} \cdot \mathbf{b} = 0$ and $\mathbf{g} \cdot \mathbf{b} \times \mathbf{u} = 0$ invisibility criteria, as shown in Fig. 2b–e. In Fig. 2b, c and d the dislocations are visible for $\mathbf{g} = (01-1)$, $\mathbf{g} = (1-10)$ and $\mathbf{g} = (1-21)$ respectively, but disappear with $\mathbf{g} = (10-1)$ in Fig. 2e, which satisfies $\mathbf{g} \cdot \mathbf{b} \times \mathbf{u} = 0$ for the dislocations being edge in character with a Burgers vector $\mathbf{b} = [1-11]$ and a line direction of $[10-1]$. The direction of the Burgers vector is plotted as a dashed green line in the stereographic projection, in Fig. 2f.

Once the dislocations have been characterized the nature of the boundary can be evaluated. Knowing the distance between the dislocations emergence points, measured on the ECC image (averaging ≈ 1010 nm), and the inclination angle of the dislocations lines ($\approx 8^\circ$), the perpendicular spacing between the individual $[10-1]$ dislocation lines making up the boundary was determined to be about $D \approx 146$ nm. With a lattice parameter of 0.29 nm resulting in a $\frac{1}{2} \langle 111 \rangle$ Burgers vector of 0.25 nm, a misorientation across the boundary can be estimated as $\theta \approx 0.1^\circ$, based on $D \approx b/\theta$.

A high accuracy EBSD map was acquired around the sub-grain boundary using an Oxford instruments EBSD system with a step size of 60 nm (this system uses hyperbola matching of the bands to enhance the accuracy, over simple Hough transform methods, to $\approx 0.05^\circ$) [28]. The disorientation relative to a reference pixel, labeled R, in the bottom of the grain is plotted in Fig. 3, revealing the existence of the sub-grain boundary and the misorientation variation in the grain of interest. A number of different areas are labeled in Fig. 3. The misorientations between these areas were determined (the orientations were determined by averaging over 220 EBSD pixels in each area). The misorientation across the boundary, measured between points A1 and B2 (approximately the locations of the HR-SACPs in Fig. 1b-1 and b-2) is $\approx 0.12^\circ$.

The misorientation across the boundary measured by high accuracy EBSD is very consistent with that measured by HR-SACPs ($\approx 0.13^\circ$) and is comparable with the misorientation calculated based on the characterization of the dislocations in the boundary ($\approx 0.1^\circ$).

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